

1.Description

EL354N is a small-sized surface mount optocoupler device suitable for surface mount production. The EL354N consists of two gallium arsenide light-emitting diodes and one phototransistor, and its size is smaller than a DIP, making it suitable for high-density surface mount applications such as programmable controllers.

2.Features

- Current transfer ratio(CTR: 20~300% at IF =5mA ,VCE =5V)
- High isolation voltage between input and output (Viso=3750 Vrms)

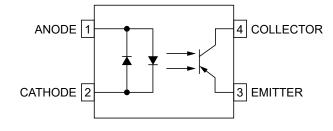
- Minimum BVCEO of 80V guaranteed
- Operation temperature:-55 to 110 °C
- Compliance with EU REACH and RoHS

3.Applications

- Switching power supply, intelligent meter
- Industrial control, measuring instruments
- Office equipment such as copiers

 Household appliances, such as air conditioners, fans, water heaters, etc.

4.Pinning Information





SOP-4







5.Absolute Maximum Ratings (T_A=25°C)

	Parameter	Symbol	Rating	Unit
	Forward Current	I _F	±50	mA
l la sout	Pulse forward current, (1µs, pulse)	I _{FP}	±1	Α
Input	Power Dissipation	P _D	70	mW
	Junction temperature	TJ	125	°C
Output	Collector Power Dissipation	Pc	150	mW
	Collector Current	Ic	50	mA
	Collector-Emitter Voltage	V _{CEO}	80	V
	Emitter-Collector Voltage	V _{ECO}	7	V
	Junction temperature	TJ	125	°C
Total Power Dissipation	on	Ртот	200	mW
Isolation Voltage		V _{ISO}	3750	Vrms
Operating Temperature			-55 to 110	°C
Storage Temperature			-55 to 125	°C
Soldering Temperatur	е	T _{SOL}	260 (10s)	°C

6.Recommended Operating Condition (Note)

Parameter	Symbol	Min	Тур	Max	Units
Supply voltage	V _{cc}	-	5	48	V
Forward current	I _F	-	16	20	mA
Collector current	Ic	-	1	10	mA

Recommended operating conditions are given as a design guideline to obtain expected performance of the device



7. Electrical Characteristics (T_A =25°C)

Parameter	Symbol	Conditions	Min	Тур	Max	Units		
Input								
Forward Voltage	V _F	I _F =±20mA	1.1	1.2	1.4	V		
Terminal Capacitance	C _{IN}	V=0, f=1kHz		30	250	pF		
Output								
Collector Dark Current	I _{CEO}	V _{CE} =20V, I _F =0mA			100	nA		
Collector-Emitter Breakdown Voltage	BV _{CEO}	I _C =0.1mA, I _F =0	80			V		
Emitter-Collector Breakdown Voltage	BV _{ECO}	I _E =0.1mA, I _F =0	7			V		
Transfer Characteristics								
Current Transfer Ratio	CTR	I _F =±1mA, V _{CE} =5V	20		300	%		
Collector-Emitter Saturation Voltage	V _{CE(sat)}	I _F =±20mA, I _C =1mA		0.1	0.2	٧		
Isolation Resistance	R _{iso}	DC500V, 40~60%R.H.	5*10 ¹⁰	1*10 ¹¹		Ω		
Floating Capacitance	C _f	V=0, f=1MHz		0.6	1	pF		
Capacitance (Collector to emitter)	C _{CE}	V=0, f=1MHz		10		pF		
Capacitance (input to output)	Cs	V=0, f=1MHz		0.8		pF		
Cut-off Frequency	Fc	V_{CE} =5V, I_{C} =2mA, R_{L} =100 Ω ,-3dB		80		kHz		
Isolation Voltage	BVs	AC,1 minute	3750			Vrms		
Switching Characteristics								
Rise Time	Tr	V _{CE} =2V, I _C =2mA			18	μs		
Fall Time	T _f	R _L =100Ω			18	μs		

^{*} CTR= I_C/I_F x 100%





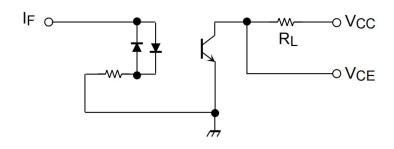


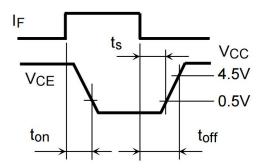


8.Rank Table of CTR

		Current Ti	ransfer Rat	io (%)(I _C /I _F)	Marking of classification	
Туре	Classification	I _F =±5m	A, V _{CE} =5V,	T _A =25°C		
		Min	Туре	Max		
	Standard	20	-	300	Blank,A,B	
EL354N	А	50	-	150	А	
	В	100	-	300	В	

9.Switching Time Test Circuit



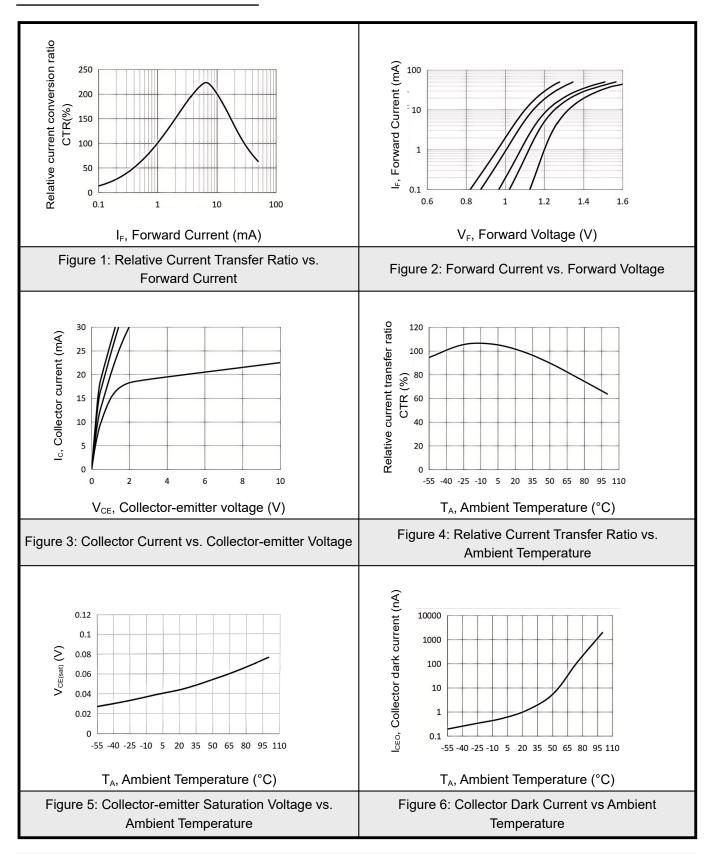








10.1 Typical Characteristic



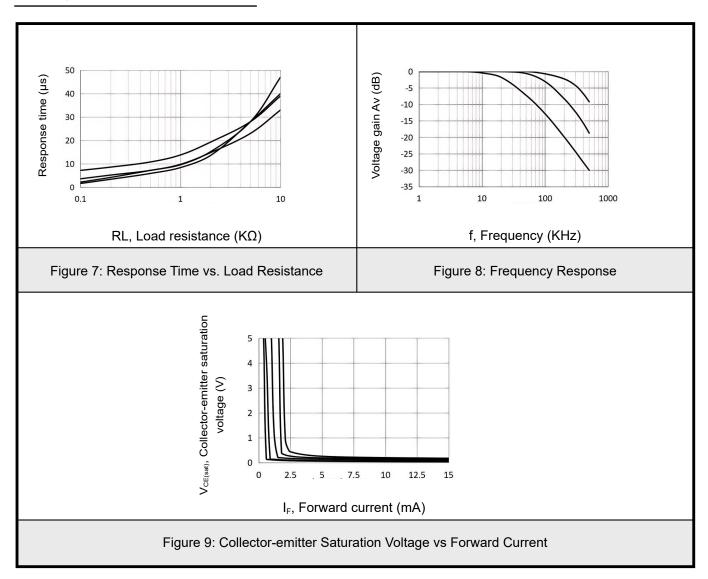








10.2 Typical Characteristic









11. Solder Reflow Profile

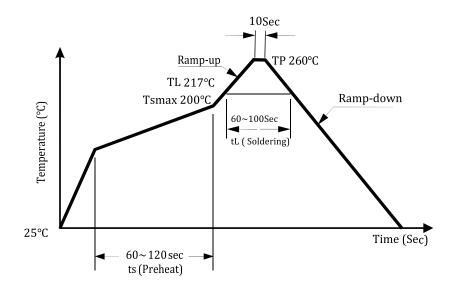
Welding precautions

Whether using a soldering iron or reflow soldering, the soldering temperature should be as close as possible to the conditions shown below. During reflow soldering

When reflow soldering does not exceed 260°C, the soldering must be completed within 10 seconds. The soldering temperature curve is based on the surface temperature of the plastic enclosure (see the figure below, with the surface temperature of the plastic enclosure as the reference)

Reflow soldering is only allowed once or twice.

After unpacking, it must be used up within 2 weeks.



· Wave soldering

It is recommended to perform one-time welding under temperature conditions.

Temperature: 260+0/-5°C

Time: 10 seconds.

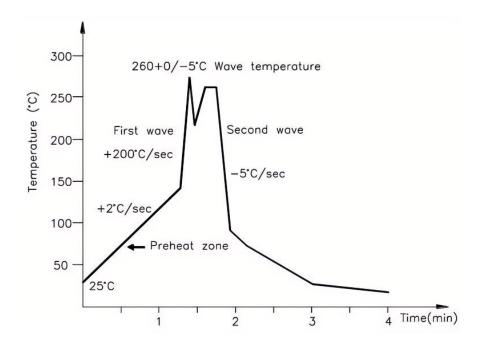
Preheating temperature: 25 to 140°C,

Preheating time: 30 to 80 seconds.



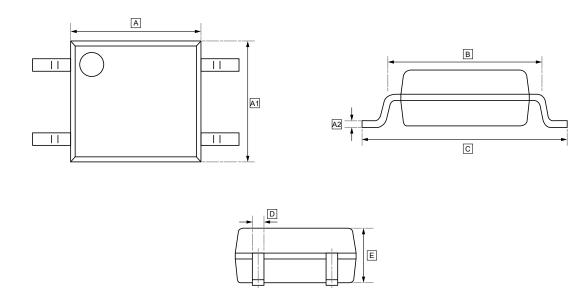








12.SOP-4 Package Outline Dimensions



DIMENSIONS (mm are the original dimensions)

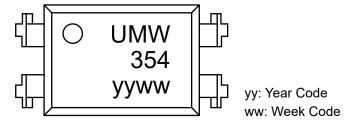
Symbol	Α	A 1	A2	В	С	D	D1	Е
Min	4.30	3.60	0.15	5.00	6.70	0.30	2.54	1.82
Max	4.50	4.10	0.15	5.40	7.30	0.50	TYP	2.02







13.Ordering Information



Order Code	Package	Base QTY	Delivery Mode	
UMW EL354N	SOP-4	3000	Tape and reel	

UMW EL354N







14.Disclaimer

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